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\_\_\_\_\_MS2222

#### **RF & MICROWAVE TRANSISTORS L – BAND RADAR APPLICATIONS**

### Features

- 1.2 1.4 GHz
- 28 VOLTS
- 5:1 VSWR CAPABILITY @ RATED CONDITIONS
- **P**<sub>OUT</sub> = 14.5 WATTS
- $G_P = 8.6 \text{ dB MINIMUM}$
- INPUT/OUTPUT MATCHING
- COMMON BASE CONFIGURATION

### **DESCRIPTION:**

The MS2222 is a NPN silicon bipolar transistor designed for L-Band pulsed radar applications.

Internal impedance matching assures consistent broadband performance and gold metalization provides maximum reliability under severe operation conditions.

The MS2222 utilizes an emitter ballasted die geometry for superior thermal stability under a wide range of pulse widths and duty cycles.

## ABSOLUTE MAXIMUM RATINGS (Tcase = 25°C)

Symbol	Parameter	Value	Unit
P <sub>DISS</sub>	Power Dissipation	37.5	W
Ι <sub>c</sub>	Device Current	1.8	Α
V <sub>CC</sub>	Collector-Supply Voltage	32	V
TJ	Junction Temperature	250	°C
T <sub>STG</sub>	Storage Temperature	-65 to +200	°C

### **Thermal Data**

	R <sub>TH(J-C)</sub>	Junction-case Thermal Resistance	4.0	°C/W
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# ELECTRICAL SPECIFICATIONS (Tcase = 25°C) STATIC

Symbol	Test Conditions			Value		
			Min.	Тур.	Max.	Onit
BV <sub>CBO</sub>	l <sub>c</sub> = 15 mA	l <sub>E</sub> = 0 mA	48			V
BV <sub>EBO</sub>	I <sub>E</sub> = 1.5 mA	$I_c = 0 mA$	3.5			V
BV <sub>CER</sub>	l <sub>c</sub> = 15 mA	R <sub>BE</sub> = 10Ω	48			v
I <sub>CES</sub>	V <sub>CE</sub> = 28 V	V <sub>BE</sub> = 28 V			1.5	mA
h <sub>FE</sub>	$V_{CE} = 5 V$	$I_{C} = 1 A$	30		300	

#### DYNAMIC

Symbol	Tost Conditions		Value			Unit	
Symbol				Min.	Тур.	Max.	Onic
Ρουτ	f = 1.2 - 1.4GHz	P <sub>IN</sub> = 2W	$V_{\rm CC} = 28V$	14.5	17		w
η <sub>c</sub>	f = 1.2 - 1.4GHz	$P_{IN} = 2W$	$V_{\rm CC} = 28V$	48	58		%
G <sub>P</sub>	f = 1.2 - 1.4GHz	$P_{IN} = 2W$	$V_{CC} = 28V$	8.6	9.3		dB

Conditions: Pulse Width =  $1000\mu$ S Duty Cycle = 10%

#### **IMPEDANCE DATA**

FREQ	$Z_{IN}(\Omega)$	$Z_{CL}(\Omega)$
1.2 GHz	3.0 + j6.5	16 + j3.0
1.3 GHz	3.5 + j7.5	13 + j6.0
1.4 GHz	5.0 + j7.0	11+ j5.0

 $\textbf{P}_{\text{IN}}$  = 2.0W ; V\_{\text{CC}} = 28V; Normalized to 50  $\Omega.$ 



### **TYPICAL PERFORMANCE**





# **TEST CIRCUIT**



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## PACKAGE MECHANICAL DATA

PACKAGE STYLE M222



	MINIMUM	MAXIMUM		MINIMUM	MAXIMUM	
	INCHES/MM	INCHES/MM		INCHES/MM	INCHES/MM	
А	.100/	/2,54	J	.562/14,28		
В	.110/	/2,80	K	.310/7,87		
С	.110/	/2,80	L	.800/20,32		
D	.296,	/7,52	М	.119/3,02		
E	.148,	/3,76	N	.050/1,27		
F		.230/5,84	0		.170/4,32	
G	.003/0,08	.006/0,15	Р	.062/1,58		
Н	.118/3,00	.131/3,33				
	.059/1,50			-		

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